

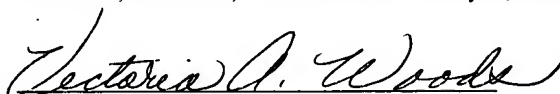


IN THE UNITED STATES PATENT AND TRADEMARK OFFICE

In re Application of:)	PATENT APPLICATION
Inventors: Jong-Jan Lee and Sheng Teng)	
Hsu)	
Serial No.: 10/625,065)	Attorney Docket No.
Filed: July 22, 2003)	SLA0696
Title: FABRICATION OF SILICON-ON-)	Customer No. 27,518
NOTHING (SON) MOSFET)	
FABRICATION USING)	
SELECTIVE ETCHING OF)	
Si _{1-x} Ge _x LAYER)	

CERTIFICATE OF MAILING UNDER 37 C.F.R. § 1.8

I hereby certify that this correspondence is being deposited in the United States Postal Service with sufficient postage as first class mail in an envelope addressed to **Commissioner for Patents, Alexandria, VA 22313-1450** on January 14, 2004:



Victoria A. Woods
Signature Date : January 14, 2004

STATUS INQUIRY

Hon. Commissioner for Patents
Alexandria, VA 22313-1450

Sir:

Applicants have not received a filing receipt for the above-identified application. Accordingly, applicants' attorney-of-record, whose name and address appear below, hereby inquires as to the status of the above-identified application.

Please direct all correspondence in this application to the following:

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Respectfully submitted,

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